A3213 and A3214

## Micropower Ultra-Sensitive Hall-Effect Switches

## FEATURES AND BENEFITS

- Micropower operation
- Operate with north or south pole
- 2.4 to 5.5 V battery operation
- Chopper stabilized
$\square$ Superior temperature stability
$\square$ Extremely low switchpoint drift
$\square$ Insensitive to physical stress
- High ESD protection
- Solid state reliability
- Small size
- Easily assembly into applications due to magnetic pole independence


## Packages:

3 pin surface mount
SOT23-W (suffix LH)

3 lead ultramini SIP (suffix UA)


Not to scale

## DESCRIPTION

The A3213 and A3214 integrated circuits are ultra-sensitive, pole independent Hall-effect switches with a latched digital output. They are especially suited for operation in batteryoperated, hand-held equipment such as cell and cordless telephones and palmtop computers. A 2.4 to 5.5 V operation and a unique clocking scheme reduce the average operating power requirements: the A 3213 to $825 \mu \mathrm{~W}$, the A 3214 to $14 \mu \mathrm{~W}$ (typical, at 2.75 V ). Except for operating duty cycle and average operating current, the A3213 and A3214 are identical.

Unlike other Hall-effect switches, either a north or south pole of sufficient strength will turn the output on; in the absence of a magnetic field, the output is off. The polarity independence and minimal power requirement allows these devices to easily replace reed switches for superior reliability and ease of manufacturing, while eliminating the requirement for signal conditioning.

Improved stability is made possible through chopper stabilization (dynamic offset cancellation), which reduces the residual offset voltage normally caused by device overmolding, temperature dependencies, and thermal stress.

Continued on the next page...


Functional Block Diagram

## Micropower Ultra-Sensitive Hall-Effect Switches

## Description (continued)

These devices include, on a single silicon chip, a Hall-voltage generator, small-signal amplifier, chopper stabilization, a latch, and a MOSFET output. Advanced BiCMOS processing is used to take advantage of low-voltage and low-power requirements, component matching, very low input-offset errors, and small component geometries.

Devices are rated for operation over a temperature range of $-40^{\circ} \mathrm{C}$ to $85^{\circ} \mathrm{C}$ or $-40^{\circ} \mathrm{C}$ to $150^{\circ} \mathrm{C}$. Two package styles provide a magnetically optimized package for most applications. 'LH' is a miniature low-profile surface-mount package, 'UA' is a threelead SIP for through-hole mounting. Each package is lead (Pb) free (suffix, -T ), with a $100 \%$ matte tin plated leadframe.

## SPECIFICATIONS

## Product Selection Guide

| Part Number | Mounting | Packing* | Ambient*, $\mathrm{T}_{\mathrm{A}}$ ( ${ }^{\circ} \mathrm{C}$ ) | $\begin{aligned} & \text { DC } \\ & \text { (\%) } \end{aligned}$ | $I_{D D(A V G)}($ typ $)$ <br> ( $\mu \mathrm{A}$ ) |
| :---: | :---: | :---: | :---: | :---: | :---: |
| A3213ELHLT-T | LH package Surface Mount | 7-in. reel 3000 pieces/reel | -40 to 85 | 25 | 309 |
| A3213ELHLX-T | LH package Surface Mount | 13-in. reel 10000 pieces/reel |  |  |  |
| A3213EUA-T | UA package SIP through hole | Bulk 500 pieces/bag |  |  |  |
| A3213LUA-T | UA package SIP through hole | Bulk <br> 500 pieces/bag | -40 to 150 |  |  |
| A3214ELHLT-T | LH package Surface Mount | 7-in. reel 3000 pieces/reel | -40 to 85 | 0.10 | 6 |
| A3214ELHLX-T | LH package Surface Mount | 13-in. reel 10000 pieces/reel |  |  |  |
| A3214EUA-T | UA package SIP through hole | Bulk <br> 500 pieces/bag |  |  |  |

*Contact Allegro for additional packing and operating temperature range options

Absolute Maximum Ratings

| Characteristic | Symbol | Notes | Rating | Units |
| :---: | :---: | :---: | :---: | :---: |
| Supply Voltage | $V_{D D}$ |  | 6 | V |
| Magnetic Flux Density | B |  | Unlimited | G |
| Output Off Voltage | $\mathrm{V}_{\text {OUT }}$ |  | 6 | V |
| Output Current | lout |  | 1 | mA |
| Operating Ambient Temperature | $\mathrm{T}_{\mathrm{A}}$ | Range E | -40 to 85 | ${ }^{\circ} \mathrm{C}$ |
|  |  | Range L | -40 to 150 | ${ }^{\circ} \mathrm{C}$ |
| Maximum Junction Temperature | $\mathrm{T}_{\mathrm{J}}$ (max) |  | 165 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature | $\mathrm{T}_{\text {stg }}$ |  | -65 to 170 | ${ }^{\circ} \mathrm{C}$ |



LH Package, 3-Pin SOT23W Pin-out Diagram


UA Package, 3-Pin SIP Pin-out Diagram

Pin-out Diagrams

| Number |  | Name |  |
| :---: | :---: | :---: | :--- |
| LH | UA |  |  |
| 1 | 1 | VDD | Input power supply; tie to GND with bypass capacitor |
| 3 | 2 | GND | Ground |
| 2 | 3 | VOUT | Output signal |

ELECTRICAL CHARACTERISTICS valid over operating voltage and temperature range, unless otherwise noted

| Characteristic | Symbol | Test Conditions | Min. | Typ. ${ }^{1}$ | Max. | Units |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Supply Voltage Range | $V_{D D}$ | Operating ${ }^{1}$ ) | 2.4 | 3.0 | 5.5 | V |
| Output Leakage Current | $\mathrm{I}_{\text {OFF }}$ | $\mathrm{V}_{\text {OUT }}=5.5 \mathrm{~V}, \mathrm{~B}_{\text {RPN }}<\mathrm{B}<\mathrm{B}_{\text {RPS }}$ | - | <1.0 | 1.0 | $\mu \mathrm{A}$ |
| Output On Voltage | $\mathrm{V}_{\text {OUT(ON) }}$ | Output on, $\mathrm{I}_{\text {OUT }}=1 \mathrm{~mA}, \mathrm{~V}_{\mathrm{DD}}=3.0 \mathrm{~V}$ | - | 100 | 300 | mV |
| Awake Time | $\mathrm{t}_{\text {awake }}$ |  | - | 60 | 90 | $\mu \mathrm{s}$ |
| Period | $\mathrm{t}_{\text {period }}$ | A3213 | - | 240 | 360 | $\mu \mathrm{s}$ |
|  |  | $\mathrm{A} 3214, \mathrm{~T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{DD}}=3 \mathrm{~V}$ | - | 60 | 90 | ms |
| Duty Cycle | DC | A3213 | - | 25 | - | \% |
|  |  | A3214 | - | 0.10 | - | \% |
| Chopping Frequency | $\mathrm{f}_{\mathrm{C}}$ |  | - | 340 | - | kHz |
| Supply Current | $\mathrm{I}_{\mathrm{DD}(\text { EN })}$ | Chip awake (enabled) | - | - | 2.0 | mA |
|  | $\mathrm{I}_{\mathrm{DD} \text { (DIS) }}$ | Chip asleep (disabled) | - | - | 8.0 | $\mu \mathrm{A}$ |
|  | $\mathrm{I}_{\mathrm{DD} \text { (AVG) }}$ | A3213 | - | 309 | 850 | $\mu \mathrm{A}$ |
|  |  | A3214 | - | 6 | 22 | $\mu \mathrm{A}$ |

${ }^{1}$ Typical Data is at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ and $\mathrm{V}_{\mathrm{DD}}=3.0 \mathrm{~V}$ and is for design information only.
${ }^{2}$ Operate and release points will vary with supply voltage. $\mathrm{B}_{\mathrm{OPx}}=$ operate point (output turns ON ); $\mathrm{B}_{\mathrm{RPx}}=$ release point (output turns OFF).

MAGNETIC CHARACTERISTICS1 valid over operating voltage and temperature range, unless otherwise noted

| Characteristic | Symbol $^{2}$ | Test Conditions | Min. | Typ. ${ }^{3}$ | Max. | Units $^{4}$ |
| :--- | :---: | :--- | :---: | :---: | :---: | :---: |
| Operate Points | $\mathrm{B}_{\text {OPS }}$ | South pole to branded side | - | 42 | 70 | G |
|  | $\mathrm{B}_{\text {OPN }}$ | North pole to branded side | -70 | -48 | - | G |
| Release Points | $\mathrm{B}_{\text {RPS }}$ | South pole to branded side | 10 | 32 | - | G |
|  | $\mathrm{B}_{\text {RPN }}$ | North pole to branded side | - | -38 | -10 | G |
| Hysteresis | $\mathrm{B}_{\text {hys }}$ | $\left\|\mathrm{B}_{\text {OPx }}-\mathrm{B}_{\text {RPx }}\right\|$ | - | 10 | - | G |

${ }^{1}$ As used here, negative flux densities are defined as less than zero (algebraic convention) and -50 G is less than +10 G .
${ }^{2} \mathrm{~B}_{\mathrm{OPx}}=$ operate point (output turns ON ); $\mathrm{B}_{\mathrm{RPx}}=$ release point (output turns OFF).
${ }^{3}$ Typical Data is at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ and $\mathrm{V}_{\mathrm{DD}}=3.0 \mathrm{~V}$ and is for design information only.
41 gauss $(\mathrm{G})$ is exactly equal to 0.1 millitesla ( mT ).

A3213 and

## Micropower Ultra-Sensitive Hall-Effect Switches

THERMAL CHARACTERISTICS may require derating at maximum conditions, see application information

| Characteristic | Symbol | Test Conditions* | Value | Units |
| :---: | :---: | :---: | :---: | :---: |
| Package Thermal Resistance | $\mathrm{R}_{\text {өJA }}$ | Package LH, 1-layer PCB with copper limited to solder pads | 228 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
|  |  | Package LH, 2-layer PCB with 0.463 in. ${ }^{2}$ of copper area each side connected by thermal vias | 110 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
|  |  | Package UA, 1-layer PCB with copper limited to solder pads | 165 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

*Additional thermal information available on Allegro website.

## Power Derating Curve




## Micropower Ultra-Sensitive Hall-Effect Switches

## TYPICAL OPERATING CHARACTERISTICS



## FUNCTIONAL DESCRIPTION

## Low Average Power

Internal timing circuitry activates the IC for $60 \mu \mathrm{~s}$ and deactivates it for the remainder of the period ( $240 \mu \mathrm{~s}$ (typ) for the A3213 and 60 ms (typ) for the A3214). A short "awake" time allows for stabilization prior to the sampling and data latching on the falling edge of the timing pulse. The output during the "sleep" time is latched in the last sampled state. The supply current is not affected by the output state.


## Chopper-Stabilized Technique

The Hall element can be considered as a resistor array similar to a Wheatstone bridge. A large portion of the offset is a result of the mismatching of these resistors. These devices use a proprietary dynamic offset cancellation technique, with an internal high-frequency clock to reduce the residual offset voltage of the Hall element that is normally caused by device overmolding, temperature dependencies, and thermal stress. The chopperstabilizing technique cancels the mismatching of the resistor circuit by changing the direction of the current flowing through the Hall plate using CMOS switches and Hall voltage measurement taps, while maintaing the Hall-voltage signal that is induced by the external magnetic flux. The signal is then captured by a sample-and-hold circuit and further processed using low-offset bipolar circuitry. This technique produces devices that have an extremely stable quiescent Hall output voltage, are immune to thermal stress, and have precise recoverability after temperature cycling. This technique will also slightly degrade the device output repeatability. A relatively high sampling frequency is used in order that faster signals can be processed.

More detailed descriptions of the circuit operation can be found in Technical Paper STP 97-10, Monolithic Magnetic Hall Sensing Using Dynamic Quadrature Offset Cancellation and Technical Paper STP 99-1, Chopper-Stabilized Amplifiers With A Track-and-Hold Signal Demodulator.


## Operation

The output of this device switches low (turns on) when a magnetic field perpendicular to the Hall element exceeds the operate point $\mathrm{B}_{\mathrm{OPS}}$ (or is less than $\mathrm{B}_{\text {OPN }}$ ). After turn-on, the output is capable of sinking up to 1 mA and the output voltage is $\mathrm{V}_{\mathrm{OUT}(\mathrm{ON})}$. When the magnetic field is reduced below the release point $B_{\text {RPS }}$ (or increased above $\mathrm{B}_{\text {RPN }}$ ), the device output switches high (turns off). The difference in the magnetic operate and release points is the hysteresis $\left(\mathrm{B}_{\text {hys }}\right)$ of the device. This built-in hysteresis allows clean switching of the output even in the presence of external mechanical vibration and electrical noise.

As used here, negative flux densities are defined as less than zero (algebraic convention) and -50 G is less than +10 G .

## A3213 and A3214

## Micropower Ultra-Sensitive Hall-Effect Switches

## Applications

Allegro's pole-independent sensing technique allows for operation with either a north pole or south pole magnet orientation, enhancing the flexibility of the device in application assembling. The technology provides the same output polarity for either pole face.

It is strongly recommended that an external bypass capacitor be connected (in close proximity to the Hall element) between the supply and ground of the device to reduce both external noise and noise generated by the chopper-stabilization technique. This is especially true due to the relatively high impedance of battery supplies.

The simplest form of magnet that will operate these devices is a bar magnet with either pole near the branded surface of the device. Many other methods of operation are possible. Extensive applications information on magnets and Hall-effect devices is also available in the Allegro application note 27701, or at
www.allegromicro.com



## Micropower Ultra-Sensitive Hall-Effect Switches

## CUSTOMER PACKAGE DRAWING

For Reference Only - Not for Tooling Use
(Reference DWG-2840)
Dimensions in millimeters - NOT TO SCALE
Dimensions exclusive of mold flash, gate burrs, and dambar protrusions Exact case and lead configuration at supplier discretion within limits shown

A) Active Area Depth, 0.43 mm
B. Reference land pattern layout; all pads a minimum of 0.20 mm from all adjacent pads; adjust as necessary to meet application process requirements and PCB layout tolerances
© Branding scale and appearance at supplier discretion
D. Hall elements, not to scale


B PCB Layout Reference View
$\mathrm{N}=$ Last three digits of device part number


$$
\mathrm{T}=\text { Temperature Code (Letter) }
$$


$\mathrm{N}=$ Last three digits of device part number
Standard Branding Reference View

Figure 1: Package LH, 3-Pin (SOT-23W)

For Reference Only - Not for Tooling Use
(Reference DWG-9049)
Dimensions in millimeters - NOT TO SCALE
Dimensions exclusive of mold flash, gate burrs, and dambar protrusions
Exact case and lead configuration at supplier discretion within limits shown


Figure 2: Package UA, 3-Pin SIP

## Revision History

| Revision | Revision Date | Description of Revision |
| :---: | :---: | :--- |
| 25 | October 29, 2012 | Update product selection |
| 26 | January 6, 2015 | Added LX option to Selection Guide |

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